NSN 5961-01-325-9474

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-325-9474 **Inclosure Material:** Glass and metal **Overall Length:** Between 0.315 inches and 0.350 inches **Terminal Length:** 1.250 inches **Overall Diameter:** 0.220 inches **Function For Which Designed:** Transient suppressor **End Application:** 5895-01-316-2747 communications system Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-13 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 18.0 reverse voltage, instantaneous and 20.0 breakdown voltage, instantaneous and 24.4 breakdown voltage, instantaneous **Current Rating Per Characteristic:** 1.00 milliamperes drain current pascal **Power Rating Per Characteristic:** 1.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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